

SN74AUP1G80

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Wide Operating V_{CC} Range of 0.8 V to 3.6 V

3.6-V I/O Tolerant to Support Mixed-Mode

Suitable for Point-to-Point Applications

ESD Performance Tested Per JESD 22

2000-V Human-Body Model

Latch-Up Performance Exceeds 100 mA Per

1000-V Charged-Device Model (C101)

Optimized for 3.3-V Operation

Signal Operation

JESD 78, Class II

 t_{pd} = 4.4 ns Max at 3.3 V

(A114-B, Class II)

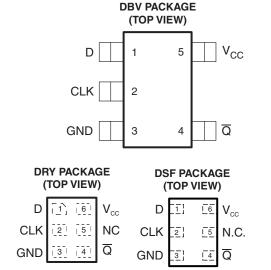
LOW-POWER SINGLE POSITIVE-EDGE-TRIGGERED D-TYPE FLIP-FLOP

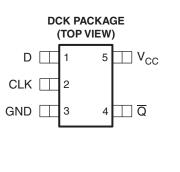
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Check for Samples: SN74AUP1G80

FEATURES

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I_{CC} = 0.9 μA Max)
- Low Dynamic-Power Consumption (C_{pd} = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C_i = 1.5 pF Typ)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- I_{off} Supports Partial-Power-Down Mode Operation
- Schmitt-Trigger Action Allows Slow Input Transition and Better Switching Noise Immunity at the Input (V_{hvs} = 250 mV Typ at 3.3 V)





YFP PACKAGE **YZP PACKAGE** (TOP VIEW) (TOP VIEW) D 6 (A2 V_{cc} D 5 (A2) V_{cc} (B) 2 5 (B2) N.C. CLK CLK GND Q GND Q (cì 3 4 (02 ci3 4 (c2

See mechanical drawings for dimensions.

N.C. – No internal connection

DESCRIPTION/ORDERING INFORMATION

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see Figure 2).



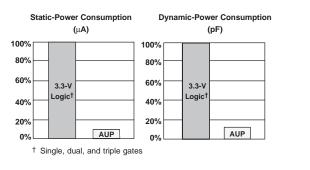
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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TEXAS INSTRUMENTS

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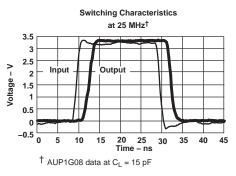


Figure 1. AUP – The Lowest-Power Family



This is a single positive-edge-triggered D-type flip-flop. When data at the data (D) input meets the setup time requirement, the data is transferred to the Q output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of the clock pulse. Following the hold-time interval, data at the D input can be changed without affecting the levels at the outputs.

NanoStar[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

O	RDERING	INFORMATIC	ON ⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoStar – WCSP (DSBGA) 0.23-mm Large Bump – YFP	Reel of 3000	SN74AUP1G80YFPR	HX_
	NanoStar – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AUP1G80YZPR	HX_
	QFN – DRY	Reel of 5000	SN74AUP1G80DRYR	НХ
–40°C to 85°C	uQFN – DSF	Reel of 5000	SN74AUP1G80DSFR	НХ
		Reel of 3000	SN74AUP1G80DBVR	1100
	SOT (SOT-23) – DBV	Reel of 250	SN74AUP1G80DBVT	— H80_
		Reel of 3000	SN74AUP1G80DCKR	
	SOT (SC-70) – DCK	Reel of 250	SN74AUP1G80DCKT	— HX_

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

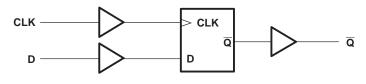
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site. YFP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

INPL	JTS	OUTPUT
CLK	D	Q
Ť	Н	L
↑	L	н
L or H	Х	\overline{Q}_0

FUNCTION TABLE

LOGIC DIAGRAM (POSITIVE LOGIC)





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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the	high-impedance or power-off state ⁽²⁾	-0.5	4.6	V
Vo	Voltage range applied to any output in the	Voltage range applied to any output in the high or low state ⁽²⁾		V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
lo	Continuous output current			±20	mA
	Continuous current through V_{CC} or GND			±50	mA
		DBV package		206	
		DCK package		252	
θ_{JA}	Package thermal impedance ⁽³⁾	DSF package		300	°C/W
		DRY package		243	
		YFP/YZP package		132	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.



RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT		
V _{CC}	Supply voltage		0.8	3.6	V		
		V _{CC} = 0.8 V	V _{CC}				
V		V_{CC} = 1.1 V to 1.95 V	$0.65 \times V_{CC}$		V		
VIH	High-level input voltage	V_{CC} = 2.3 V to 2.7 V	1.6		v		
		V_{CC} = 3 V to 3.6 V	2				
		$V_{CC} = 0.8 V$		0			
\ <i>\</i>		V_{CC} = 1.1 V to 1.95 V		$0.35 \times V_{CC}$	V		
V _{IL}	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	v		
		V_{CC} = 3 V to 3.6 V		0.9			
VI	Input voltage		0	3.6	V		
Vo	Output voltage		0	V _{CC}	V		
		V _{CC} = 0.8 V		-20	μA		
		V _{CC} = 1.1 V		-1.1			
	High-level output current ⁽²⁾	$V_{CC} = 1.4 V$		-1.7			
I _{ОН}	High-level output current	V _{CC} = 1.65		-1.9	mA		
		$V_{CC} = 2.3 V$		-3.1			
		$V_{CC} = 3 V$		-4			
		$V_{CC} = 0.8 V$		20	μA		
		V _{CC} = 1.1 V		1.1			
	Low-level output current ⁽²⁾	$V_{CC} = 1.4 V$		1.7			
I _{OL}		V _{CC} = 1.65 V		1.9			
		V _{CC} = 2.3 V		3.1			
		V _{CC} = 3 V		4			
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 0.8 V \text{ to } 3.6 V$		200	ns/V		
T _A	Operating free-air temperature	*	-40	85	°C		

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

(2) Defined by the signal integrity requirements and design-goal priorities.



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ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	т,	_A = 25°C	T _A = −40°C to 85°C	UNIT
			MIN	TYP MAX	MIN MAX	
	I _{OH} = -20 μA	0.8 V to 3.6 V	V _{CC} – 0.1		V _{CC} – 0.1	
	I _{OH} = -1.1 mA	1.1 V	0.75 × V _{CC}		$0.7 \times V_{CC}$	
	I _{OH} = -1.7 mA	1.4 V	1.11		1.03	
V _{OH}	I _{OH} = -1.9 mA	1.65 V	1.32		1.3	V
	I _{OH} = -2.3 mA	2.2.1/	2.05		1.97	
	I _{OH} = -3.1 mA	2.3 V	1.9		1.85	
	I _{OH} = -2.7 mA	0.14	2.72		2.67	
	$I_{OH} = -4 \text{ mA}$	- 3 V	2.6		2.55	
	I _{OL} = 20 μA	0.8 V to 3.6 V		0.1	0.1	
	I _{OL} = 1.1 mA	1.1 V		0.3 × V _{CC}	0.3 × V _{CC}	
	I _{OL} = 1.7 mA	1.4 V		0.31	0.37	
	I _{OL} = 1.9 mA	1.65 V		0.31	0.35	v
V _{OL}	I _{OL} = 2.3 mA			0.31	0.33	V
	I _{OL} = 3.1 mA	2.3 V		0.44	0.45	
	I _{OL} = 2.7 mA	2.14		0.31	0.33	
	I _{OL} = 4 mA	- 3 V		0.44	0.45	
II D or CLK input	$V_{I} = GND$ to 3.6 V	0 V to 3.6 V		0.1	0.5	μA
l _{off}	V_{I} or $V_{O} = 0$ V to 3.6 V	0 V		0.2	0.6	μA
Δl _{off}	V_{I} or $V_{O} = 0$ V to 3.6 V	0 V to 0.2 V		0.2	0.6	μA
Icc	$V_{I} = GND \text{ or } V_{CC} \text{ to } 3.6 \text{ V}, I_{O} = 0$	0.8 V to 3.6 V		0.5	0.9	μA
ΔI _{CC}	$V_{I} = V_{CC} - 0.6 V$, ⁽¹⁾ $I_{O} = 0$	3.3 V		40	50	μA
0		0 V		1.5		- 5
Ci	$V_I = V_{CC}$ or GND	3.6 V		1.5		pF
Co	V _O = GND	0 V		3		pF

(1) One input at V_{CC} – 0.6 V, other input at V_{CC} or GND



TIMING REQUIREMENTS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

			V _{cc}	T _A = 25°C	T _A = -4 to 85	T _A = -40°C to 85°C	
				ТҮР	MIN	MAX	
			0.8 V			20	
			1.2 V ± 0.1 V			80	
ſ	Cleak fragmanau		1.5 V ± 0.1 V			120	MHz
f _{clock}	Clock frequency		1.8 V ± 0.15 V			160	
			2.5 V ± 0.2 V			220	
			3.3 V ± 0.3 V			260	
			0.8 V		5.5		
			1.2 V ± 0.1 V		2.5		
	Dulas duration CLK high and		1.5 V ± 0.1 V		1.5		
t _w	Pulse duration, CLK high or lo	JW .	1.8 V ± 0.15 V		1.6		
			2.5 V ± 0.2 V		1.7		
			3.3 V ± 0.3 V		1.9		
			0.8 V	3.4	6.7		
			1.2 V ± 0.1 V		2.4		
		Data hish	1.5 V ± 0.1 V		1.2		
		Data high	1.8 V ± 0.15 V		0.8		ns
			2.5 V ± 0.2 V		0.6		
			3.3 V ± 0.3 V		0.4		
t _{su}	Setup time before CLK↑		0.8 V	3.4	8.9		
			1.2 V ± 0.1 V		2		
		Dete law	1.5 V ± 0.1 V		1.3		
		Data low	1.8 V ± 0.15 V		1.1		ns
			2.5 V ± 0.2 V		0.8		
			3.3 V ± 0.3 V		0.7		
			0.8 V	0	1		
			1.2 V ± 0.1 V		0		
	Light time, data after OLIC		1.5 V ± 0.1 V		0		
t _h	Hold time, data after CLK↑		1.8 V ± 0.15 V		0		ns
			2.5 V ± 0.2 V		0		
			3.3 V ± 0.3 V		0		



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	T) (OUTPUT) ^V CC	V _{cc}	т	T _A = 25°C			40°C 5°C	UNIT
			MIN	TYP	MAX	MIN	MAX		
			0.8 V		91		90		
			1.2 V ± 0.1 V		175		220		
4			1.5 V ± 0.1 V		237		230		MHz
f _{max}			1.8 V ± 0.15 V		269		240		IVIHZ
			2.5 V ± 0.2 V		280		250		
			3.3 V ± 0.3 V		280		260		
			0.8 V		17.2				
			1.2 V ± 0.1 V	3.2	7.1	14.9	2.7	16.3	
		ā	1.5 V ± 0.1 V	1.9	5	9.8	2.1	10.3	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	1.7	3.9	7.6	1.6	8.1	ns
			2.5 V ± 0.2 V	1.4	2.8	5.3	1.2	5.6	
			3.3 V ± 0.3 V	1.2	2.2	4.1	1	4.4	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO	V _{cc}	T _A = 25°C			T _A = -40°C to 85°C		UNIT
	(INPUT)	UT) (OUTPUT)		MIN	TYP	MAX	MIN	MAX	
			0.8 V		68		70		
			1.2 V ± 0.1 V		128		170		
4			1.5 V ± 0.1 V		189		220		MHz
f _{max}			1.8 V ± 0.15 V		234		240		WHZ
			2.5 V ± 0.2 V		273		250		
			3.3 V ± 0.3 V		280		260		
			0.8 V		19.4				
			1.2 V ± 0.1 V	4.4	8.2	16.2	3.4	17.7	
		ā	1.5 V ± 0.1 V	3.6	5.8	10.7	2.6	11.3	
t _{pd}	CLK	CLK Q	1.8 V ± 0.15 V	2.9	4.6	8.4	2.1	3	ns
			2.5 V ± 0.2 V	2.2	3.3	5.9	1.7	6.3	
			3.3 V ± 0.3 V	1.9	2.7	4.7	1.4	4.9	



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SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	TO (OUTPUT)	V _{cc}	т,	T _A = 25°C			T _A = -40°C to 85°C	
	(INPUT)			MIN	TYP	MAX	MIN	MAX	
			0.8 V		52		50		
			1.2 V ± 0.1 V		98		130		
4			1.5 V ± 0.1 V		148		180		MHz
f _{max}			1.8 V ± 0.15 V		196		240		IVIEZ
			2.5 V ± 0.2 V		249		250		
			3.3 V ± 0.3 V		280		260		
			0.8 V		21.5				
			1.2 V ± 0.1 V	3	9.1	17.4	4.1	19	
		Q	1.5 V ± 0.1 V	3.2	6.5	11.7	3.2	12.3	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	2.7	4.2	9.2	2.6	9.8	ns
			2.5 V ± 0.2 V	2.2	3.8	6.5	2.1	6.9	
			3.3 V ± 0.3 V	1.9	3.1	5.1	1.8	5.5	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	FROM TO (INPUT) (OUTPUT)	V _{cc}	T _A = 25°C			T _A = −40°C to 85°C		UNIT
	(INFOT)				MIN	TYP	MAX	MIN	MAX
			0.8 V		32		20		
			1.2 V ± 0.1 V		71		80		
4			1.5 V ± 0.1 V		104		120		MHz
f _{max}			1.8 V ± 0.15 V		133		160		IVITIZ
			2.5 V ± 0.2 V		181		220		
			3.3 V ± 0.3 V		257		260		
			0.8 V		28.4				
			1.2 V ± 0.1 V	5.1	11.8	20.7	6.2	28.7	
		ā	1.5 V ± 0.1 V	4.8	8.5	14.1	6.9	16.7	
t _{pd}	CLK	Q	1.8 V ± 0.15 V	4	6.9	11.2	2	13.3	ns
			2.5 V ± 0.2 V	3.3	5.1	7.9	3.2	9.3	
			3.3 V ± 0.3 V	2.9	4.2	6.4	2.8	7.5	ſ

OPERATING CHARACTERISTICS

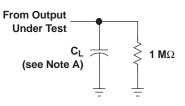
 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	
	C _{pd} Power dissipation capacitance	f = 10 MHz	1.2 V ± 0.1 V	4	pF
<u> </u>			1.5 V ± 0.1 V	4	
C _{pd}			1.8 V ± 0.15 V	4	
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	



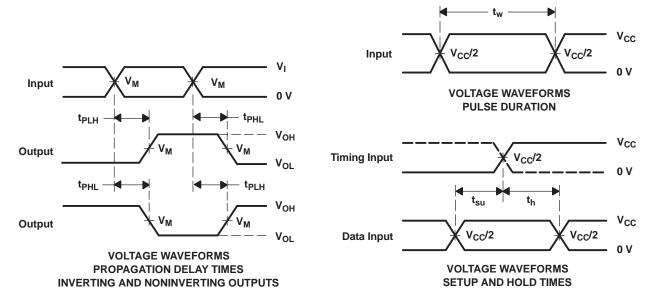
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PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Duration)



	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}

LOAD CIRCUIT



NOTES: A. C_L includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_r/t_f = 3 ns.

C. The outputs are measured one at a time, with one transition per measurement.

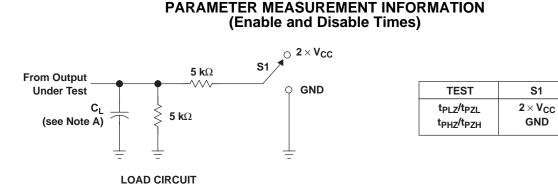
- D. t_{PLH} and t_{PHL} are the same as t_{pd} .
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

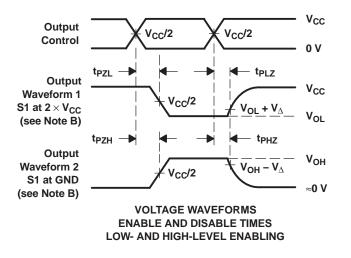
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	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
С _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _Δ	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f/t_f = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- t_{PZL} and t_{PZH} are the same as t_{en} . F.
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms



26-Mar-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74AUP1G80DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H80R	Samples
SN74AUP1G80DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H80R	Samples
SN74AUP1G80DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H80R	Samples
SN74AUP1G80DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H80R	Samples
SN74AUP1G80DBVTE4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H80R	Samples
SN74AUP1G80DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H80R	Samples
SN74AUP1G80DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HX5 ~ HXF ~ HXK ~ HXO ~ HXR)	Samples
SN74AUP1G80DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HX5 ~ HXF ~ HXK ~ HXO ~ HXR)	Samples
SN74AUP1G80DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HX5 ~ HXF ~ HXK ~ HXO ~ HXR)	Samples
SN74AUP1G80DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HX5 ~ HXO ~ HXR)	Samples
SN74AUP1G80DCKTE4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HX5 ~ HXO ~ HXR)	Samples
SN74AUP1G80DCKTG4	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HX5 ~ HXO ~ HXR)	Samples
SN74AUP1G80DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	НХ	Samples
SN74AUP1G80DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	НХ	Samples
SN74AUP1G80YFPR	ACTIVE	DSBGA	YFP	6	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM		(HX2 ~ HXN)	Samples
SN74AUP1G80YZPR	ACTIVE	DSBGA	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(HX7 ~ HXN)	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.





26-Mar-2013

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



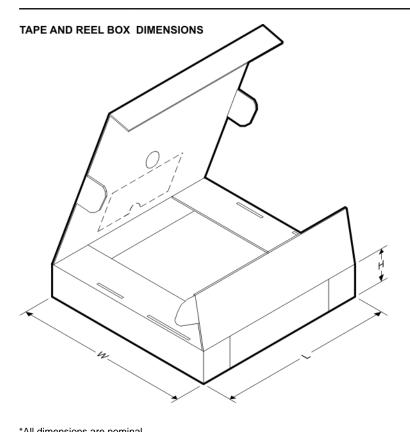
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G80DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G80DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G80DCKR	SC70	DCK	5	3000	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AUP1G80DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G80DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G80DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G80DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G80YFPR	DSBGA	YFP	6	3000	178.0	9.2	0.89	1.29	0.62	4.0	8.0	Q1
SN74AUP1G80YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

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PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G80DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G80DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G80DCKR	SC70	DCK	5	3000	205.0	200.0	33.0
SN74AUP1G80DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AUP1G80DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AUP1G80DRYR	SON	DRY	6	5000	180.0	180.0	30.0
SN74AUP1G80DSFR	SON	DSF	6	5000	180.0	180.0	30.0
SN74AUP1G80YFPR	DSBGA	YFP	6	3000	220.0	220.0	35.0
SN74AUP1G80YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



MECHANICAL DATA



- C. SON (Small Outline No-Lead) package configuration.
- Δ The exposed lead frame feature on side of package may or may not be present due to alternative lead frame designs.
- E. This package complies to JEDEC MO-287 variation UFAD.
- 🖄 See the additional figure in the Product Data Sheet for details regarding the pin 1 identifier shape.



DRY (R-PUSON-N6)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.

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MECHANICAL DATA



- - B. This drawing is subject to change without notice.
 C. SON (Small Outline No-Lead) package configuration.
 D. This package complies to JEDEC M0-287 variation X2AAF.





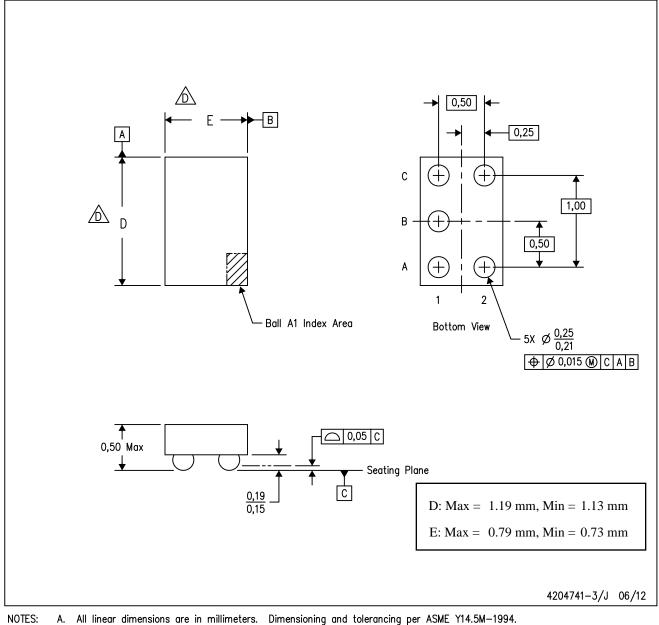
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



YZP (R-XBGA-N5)

DIE-SIZE BALL GRID ARRAY



- Α.
- Β. This drawing is subject to change without notice. C. NanoFree™ package configuration.
- The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative. E. This package is a Pb-free solder ball design. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

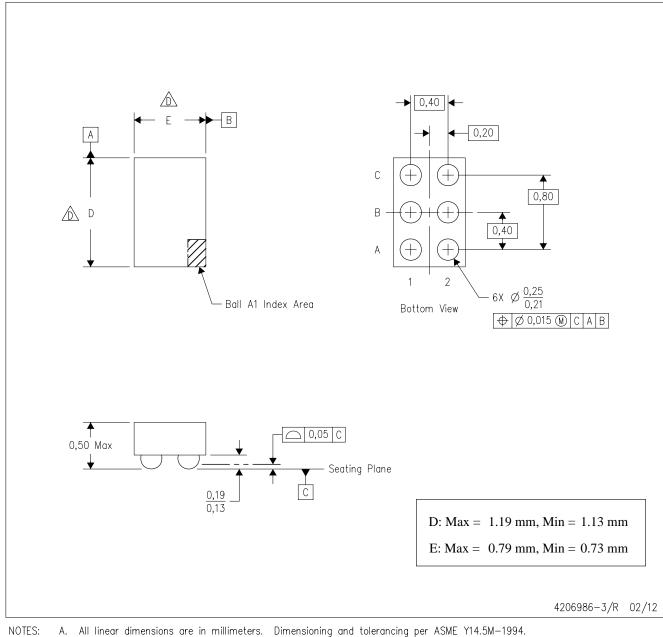
NanoFree is a trademark of Texas Instruments.



MECHANICAL DATA

YFP (R-XBGA-N6)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- The package size (Dimension D and E) of a particular device is specified in the device Product Data Sheet version of this drawing, in case it cannot be found in the product data sheet please contact a local TI representative.
- E. Reference Product Data Sheet for array population.
- 2 x 3 matrix pattern is shown for illustration only.
- F. This package contains Pb-free balls.

NanoFree is a trademark of Texas Instruments



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Наши контакты:

Телефон: +7 812 627 14 35

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